Precision Monolithic Low-Voltage CMOS Analog Switches

DESCRIPTION

The DG417L, DG418L, DG419L are low voltage pin-for-pin compatible companion devices to the industry standard DG417, DG418, DG419 with improved performance.

Using BiCMOS wafer fabrication technology allows the DG417L, DG418L, DG419L to operate on single and dual supplies. Single supply voltage ranges from 3 V to 12 V while dual supply operation is recommended with ± 3 V to ± 6 V.

Combining high speed (t_{ON}: 28 ns), flat R_{ON} over the analog signal range (6 Ω), minimal insertion lose (up to 100 MHz), and excellent crosstalk and off-isolation performance (- 70 dB at 1 MHz), the DG417L, DG418L, DG419L are ideally suited for audio and video signal switching.

The DG417L and DG418L respond to opposite control logic as shown in the truth table. The DG419L has an SPDT configuration.

FEATURES

- 2.7 V- thru 12 V single supply or ± 3- thru ± 6 dual supply
- On-resistance - R_{ON}: 14 Ω
- Fast switching - t_{ON}: 28 ns
  - t_{OFF}: 13 ns
- TTL, CMOS compatible
- Low leakage: < 100 pA
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

Pb-free Available

RoHS* Available

APPLICATIONS

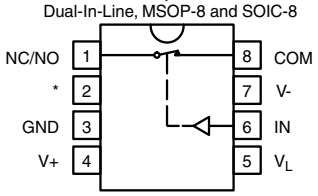
- Precision automatic test equipment
- Precision data acquisition
- Communication systems
- Battery powered systems
- Computer peripherals
- SDSL, DSLAM
- Audio and video signal routing

BENEFITS

- Widest dynamic range
- Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

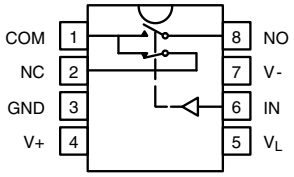
DG417L, DG418L
Dual-In-Line, MSOP-8 and SOIC-8



Top View

* Not Connected

DG419L
Dual-In-Line, MSOP-8 and SOIC-8



Top View

TRUTH TABLE		
Logic	**DG417L**	**DG418L**
0	ON	OFF
1	OFF	ON

TRUTH TABLE (DG419L)		
Logic	**NC**	**NO**
0	ON	OFF
1	OFF	ON

ORDERING INFORMATION (DG417L, DG418L)		
Temp. Range	**Package**	**Part Number**
	8-Pin Narrow SOIC	DG417LDY DG417LDY-E3 DG417LDY-T1 DG417LDY-T1-E3
		DG418LDY DG418LDY-E3 DG418LDY-T1 DG418LDY-T1-E3
	8-Pin MSOP	DG417LDQ-T1-E3
		DG418LDQ-T1-E3

ORDERING INFORMATION (DG419L)		
Temp. Range	**Package**	**Part Number**
- 40 °C to 85 °C	8-Pin Narrow SOIC	DG419LDY DG419LDY-E3 DG419LDY-T1 DG419LDY-T1-E3
	8-Pin MSOP	DG419LDQ-T1-E3

* Pb containing terminations are not RoHS compliant, exemptions may apply

ABSOLUTE MAXIMUM RATINGS

Parameter		Limit	Unit
V+ to V-		- 0.3 to 13	V
GND to V-		7	
V_L		(GND - 0.3) to (V+) + 0.3	
I_N, COM, NC, NO[a]		- 0.3 to (V+ + 0.3) or 30 mA, whichever occurs first	
Continuous Current (Any Terminal)		30	mA
Peak Current, S or D (Pulsed 1 ms, 10 % Duty Cycle)		100	
Storage Temperature	(AK, DQ, DY Suffix)	- 65 to 150	°C
Power Dissipation (Packages)[b]	8-Pin MSOP[c]	320	mW
	8-Pin SOIC[c]	400	
	8-Pin CerDIP[d]	600	

Notes:
a. Signals on NC, NO, COM, or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC board.
c. Derate 6.5 mW/°C above 25 °C.
d. Derate 12 mW/°C above 75 °C.

SPECIFICATIONS (Single Supply 12 V)

Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 12 V, V- = 0 V V_L = 5 V, V_{IN} = 2.4 V, 0.8 V[f]	Temp.[b]	Typ.[c]	A Suffix Limits - 55 °C to 125 °C Min.[d]	A Suffix Limits - 55 °C to 125 °C Max.[d]	D Suffix Limits - 40 °C to 85 °C Min.[d]	D Suffix Limits - 40 °C to 85 °C Max.[d]	Unit
Analog Switch									
Analog Signal Range[e]	V_{ANALOG}		Full		0	12	0	12	V
On-Resistance	R_{ON}	V+ = 10.8 V, V- = 0 V I_{NO}, I_{NC} = 5 mA, V_{COM} = 2 V / 9 V	Room Full	13		20 32		20 23.5	Ω
Switch Off Leakage Current	$I_{NO(off)}$ $I_{NC(off)}$	V_{COM} = 1 V / 11 V V_{NO}, V_{NC} = 11 V / 1 V	Room Full		- 1 - 15	1 15	- 1 - 10	1 10	nA
	$I_{COM(off)}$		Room Full		- 1 - 15	1 15	- 1 - 10	1 10	
Channel On Leakage Current	$I_{COM(on)}$	V_{NO}, V_{NC} = V_{COM} = 11 V / 1 V	Room Full		- 1 - 15	1 15	- 1 - 10	1 10	
Digital Control									
Input Current	I_{INL} or I_{INH}		Full	0.01	- 1.5	1.5	- 1	1	µA
Dynamic Characteristics									
Turn-On Time	t_{ON}	R_L = 300 Ω, C_L = 35 pF V_{NO}, V_{NC} = 5 V, see figure 2	Room Full	28		43 50		43 46	ns
Turn-Off Time	t_{OFF}		Room Full	13		31 35		31 32	
Break-Before-Make Time Delay	t_D	DG419L only, V_{NC}, V_{NO} = 5 V R_L = 300 Ω, C_L = 35 pF	Room	13					
Charge Injection[e]	Q_{INJ}	V_g = 0 V, R_g = 0 Ω, C_L = 1 nF	Room	1					pC
Off-Isolation[e]	OIRR	R_L = 50 Ω, C_L = 5 pF , f = 1 MHz	Room	- 71					dB
Channel-to-Channel Crosstalk[e]	X_{TALK}		Room	- 71					
Source Off Capacitance[e]	$C_{NO(off)}$ $C_{NC(off)}$	V_{IN} = 0 or V+, f = 1 MHz	Room	5					pF
Channel-On Capacitance[e]	C_{ON}		Room	15					
Power Supplies									
Positive Supply Current	I+	V_{IN} = 0 or V_L	Room Full	0.02		1 7.5		1 5	µA
Negative Supply Current	I-		Room Full	- 0.002	- 1 - 7.5		- 1 - 5		
Logic Supply Current	I_L		Room Full	0.002		1 7.5		1 5	
Ground Current	I_{GND}		Room Full	- 0.002	- 1 - 7.5		- 1 - 5		

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SPECIFICATIONS (Dual Supply ± 5 V)									
		Test Conditions Unless Otherwise Specified V+ = 5 V, V- = - 5 V V_L = 5 V, V_{IN} = 2.4 V, 0.8 V[f]			**A Suffix Limits** - 55 °C to 125 °C		**D Suffix Limits** - 40 °C to 85 °C		
Parameter	**Symbol**		**Temp.[b]**	**Typ.[c]**	**Min.[d]**	**Max.[d]**	**Min.[d]**	**Max.[d]**	**Unit**
Analog Switch									
Analog Signal Range[e]	V_{ANALOG}		Full		- 5	5	- 5	5	V
On-Resistance	R_{ON}	V+ = 5 V, V- = - 5 V I_{NO}, I_{NC} = 5 mA, V_{COM} = ± 3.5 V	Room Full	14		18.5 30		18.5 21	Ω
Switch Off Leakage Current[a]	$I_{NO(off)}$ $I_{NC(off)}$	V+ = 5.5 , V- = - 5.5 V V_{COM} = ± 4.5 V V_{NO}, V_{NC} = ± 4.5 V	Room Full		- 1 - 15	1 15	- 1 - 10	1 10	nA
	$I_{COM(off)}$		Room Full		- 1 - 15	1 15	- 1 - 10	1 10	
Channel On Leakage Current[a]	$I_{COM(on)}$	V+ = 5.5 V, V- = - 5.5 V V_{NO}, V_{NC} = V_{COM} = ± 4.5 V	Room Full		- 1 - 15	1 15	- 1 - 10	1 10	
Digital Control									
Input Current[a]	I_{INL} or I_{INH}		Full	0.05	- 1.5	1.5	- 1	1	µA
Dynamic Characteristics									
Turn-On Time[e]	t_{ON}	R_L = 300 Ω, C_L = 35 pF V_{NO}, V_{NC} = ± 3.5 V, see figure 2	Room Full	30		41 50		41 44	ns
Turn-Off Time[e]	t_{OFF}		Room Full	16		32 36		32 33	
Break-Before-Make Time Delay[e]	t_D	DG419L only, V_{NO}, V_{NC} = 3.5 V R_L = 300 Ω, C_L = 35 pF	Room	10					
TransitionTime	t_{TRANS}	R_L = 300 Ω, C_L = 35 pF V_{S1} = ± 3.5 V, V_{S2} = ± 3.5 V	Room	33		47		47	
Charge Injection[e]	Q_{INJ}	V_g = 0 V, R_g = 0 Ω, C_L = 1 nF	Room	3					pC
Off-Isolation[e]	OIRR	R_L = 50 Ω, C_L = 5 pF , f = 1 MHz	Room	- 71					dB
Channel-to-Channel Crosstalk[e]	X_{TALK}		Room	- 76					
Source Off Capacitance[e]	$C_{NO(off)}$ $C_{NC(off)}$	f = 1 MHz	Room	5.2					pF
Channel-On Capacitance[e]	C_{ON}		Room	15					
Power Supplies									
Positive Supply Current[e]	I+	V_{IN} = 0 or V_L	Room Full	0.03		1 7.5		1 5	µA
Negative Supply Current[e]	I-		Room Full	- 0.002	- 1 - 7.5		- 1 - 5		
Logic Supply Current[e]	I_L		Room Full	0.002		1 7.5		1 5	
Ground Current[e]	I_{GND}		Room Full	- 0.002	- 1 - 7.5		- 1 - 5		

SPECIFICATIONS (Single Supply 5 V)									
Parameter	**Symbol**	**Test Conditions Unless Otherwise Specified** V+ = 5 V, V- = 0 V V_L = 5 V, V_{IN} = 2.4 V, 0.8 V[f]	**Temp.[b]**	**Typ.[c]**	**A Suffix Limits** - 55 °C to 125 °C **Min.[d]**	**Max.[d]**	**D Suffix Limits** - 40 °C to 85 °C **Min.[d]**	**Max.[d]**	**Unit**
Analog Switch									
Analog Signal Range[e]	V_{ANALOG}		Full			5		5	V
On-Resistance[e]	R_{ON}	V+ = 4.5 V, I_{NO}, I_{NC} = 5 mA V_{COM} = 1 V, 3.5 V	Room Full	26		36.5 50		36.5 40.5	Ω
Dynamic Characteristics									
Turn-On Time[e]	t_{ON}	R_L = 300 Ω, C_L = 35 pF V_{NO}, V_{NC} = 3.5 V, see figure 2	Room Full	37		49 60		49 54	ns
Turn-Off Time[e]	t_{OFF}		Room Full	16		31 35		31 32	
Break-Before-Make Time Delay[e]	t_D	DG419L only, V_{NO}, V_{NC} = 3.5 V R_L = 300 Ω, C_L = 35 pF	Room	19					
Charge Injection[e]	Q_{INJ}	V_g = 0 V, R_g = 0 Ω, C_L = 1 nF	Room	0.4					pC
Power Supplies									
Positive Supply Current[e]	I+	V_{IN} = 0 or V_L	Room Full	0.02		1 7.5		1 5	µA
Negative Supply Current[e]	I-		Room Full	- 0.002	- 1 - 7.5		- 1 - 5		
Logic Supply Current[e]	I_L		Room Full	0.002		1 7.5		1 5	
Ground Current[e]	I_{GND}		Room Full	- 0.002	- 1 - 7.5		- 1 - 5		

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SPECIFICATIONS (Single Supply 3 V)								
Parameter	**Symbol**	**Test Conditions Unless Otherwise Specified** V+ = 3 V, V- = 0 V V_L = 3 V, V_{IN} = 2 V, 0.4 V[f]	**Temp.[b]**	**Typ.[c]**	**A Suffix Limits** - 55 °C to 125 °C **Min.[d]**	**A Suffix Limits** - 55 °C to 125 °C **Max.[d]**	**D Suffix Limits** - 40 °C to 85 °C **Min.[d]**	**D Suffix Limits** - 40 °C to 85 °C **Max.[d]**	**Unit**
Analog Switch									
Analog Signal Range[e]	V_{ANALOG}		Full		0	3	0	3	V
On-Resistance	R_{ON}	V+ = 2.7 V, V- = 0 V I_{NO}, I_{NC} = 5 mA, V_{COM} = 0.5 V, 2.2 V	Room Full	47		70 80		70 75	Ω
Switch Off Leakage Current[a]	$I_{NO(off)}$ $I_{NC(off)}$	V+ = 3.3 , V- = 0 V V_{COM} = 1, 2 V, V_{NO}, V_{NC} = 2, 1 V	Room Full		- 1 - 15	1 15	- 1 - 10	1 10	nA
	$I_{COM(off)}$		Room Full		- 1 - 15	1 15	- 1 - 10	1 10	
Channel On Leakage Current[a]	$I_{COM(on)}$	V+ = 3.3 V, V- = 0 V V_{NO}, V_{NC} = V_{COM} = 1 V, 2 V	Room Full		- 1 - 15	1 15	- 1 - 10	1 10	
Digital Control									
Input Current[a]	I_{INL} or I_{INH}		Full	0.005	- 1.5	1.5	- 1	1	µA
Dynamic Characteristics									
Turn-On Time	t_{ON}	R_L = 300 Ω, C_L = 35 pF V_{NO}, V_{NC} = 1.5 V, see figure 2	Room Full	65		75 95		75 85	ns
Turn-Off Time	t_{OFF}		Room Full	26		41 45		41 43	
Break-Before-Make Time Delay	t_D	DG419L only, V_{NO}, V_{NC} = 1.5 V R_L = 300 Ω, C_L = 35 pF	Room	33					
Charge Injection[e]	Q_{INJ}	V_g = 0 V, R_g = 0 Ω, C_L = 10 nF	Room	1					pC
Off-Isolation[e]	OIRR	R_L = 50 Ω, C_L = 5 pF , f = 1 MHz	Room	- 71					dB
Channel-to-Channel Crosstalk[e]	X_{TALK}		Room	- 77					
Source Off Capacitance[e]	$C_{NO(off)}$ $C_{NC(off)}$	f = 1 MHz	Room	5.6					pF
Channel On Capacitance[e]	$C_{D(on)}$		Room	16					

Notes:

a. Leakage parameters are guaranteed by worst case test condition and not subject to production test.

b. Room = 25 °C, Full = as determined by the operating temperature suffix.

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

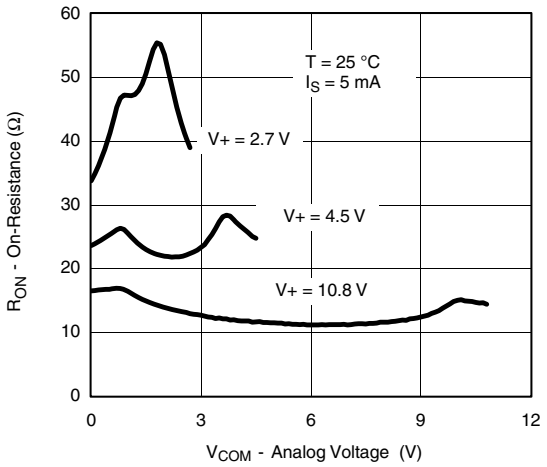
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

e. Guaranteed by design, not subject to production test.

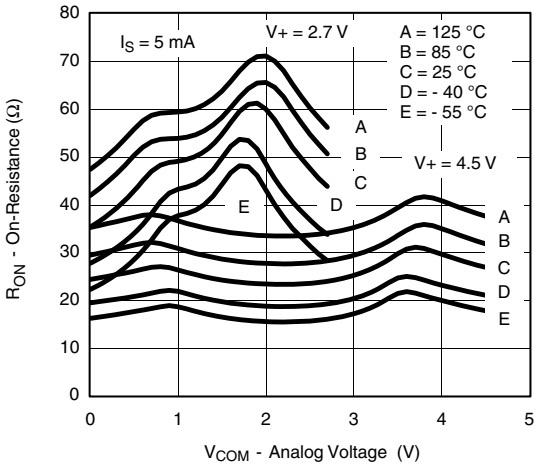
f. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

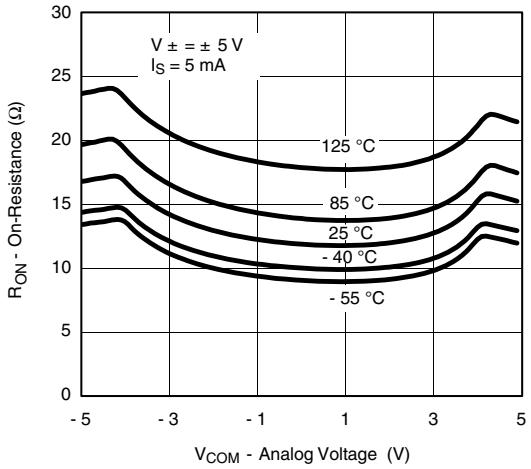
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



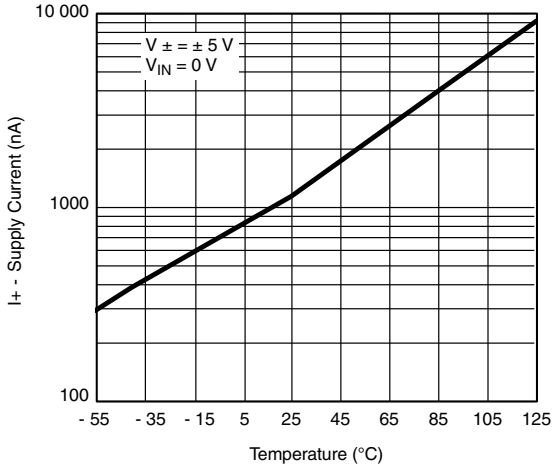
R_{ON} vs. V_{COM} and Supply Voltage



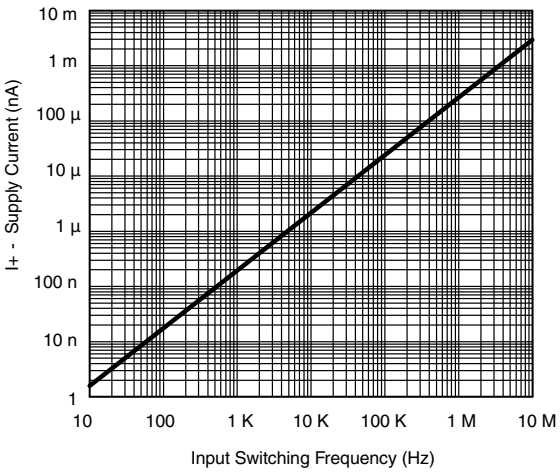
R_{ON} vs. Analog Voltage and Temperature



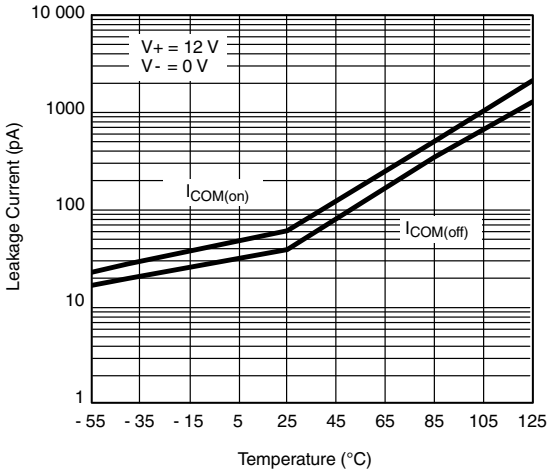
R_{ON} vs. Analog Voltage and Temperature



Supply Current vs. Temperature



Supply Current vs. Input Switching Frequency



Leakage Current vs. Temperature

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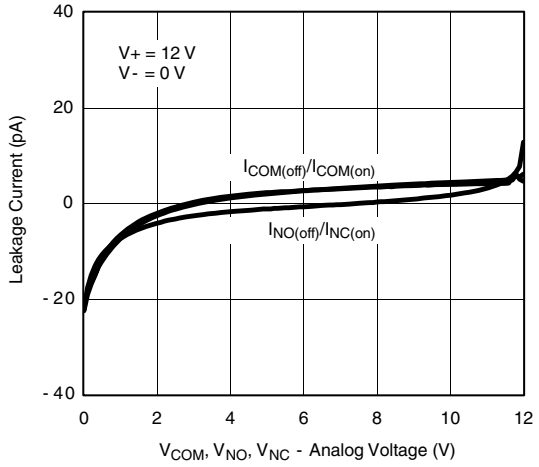
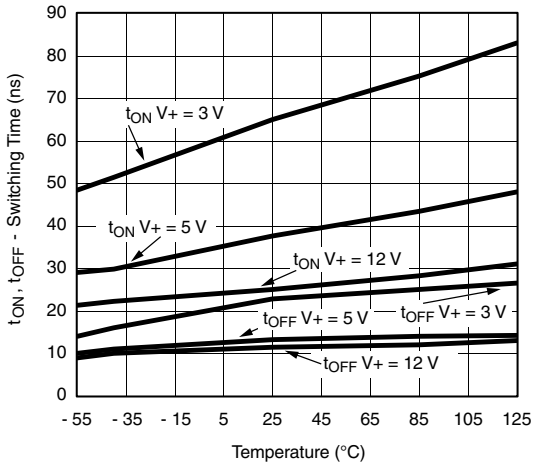
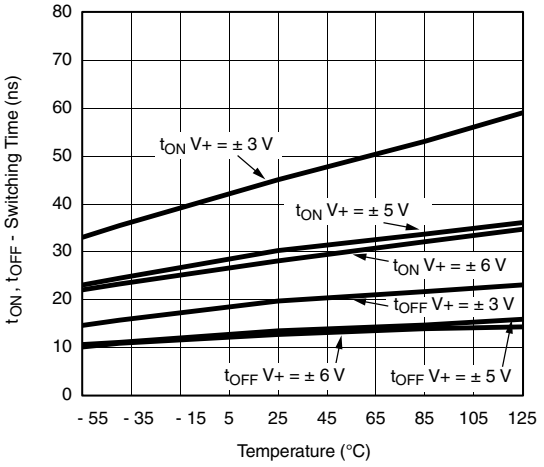
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



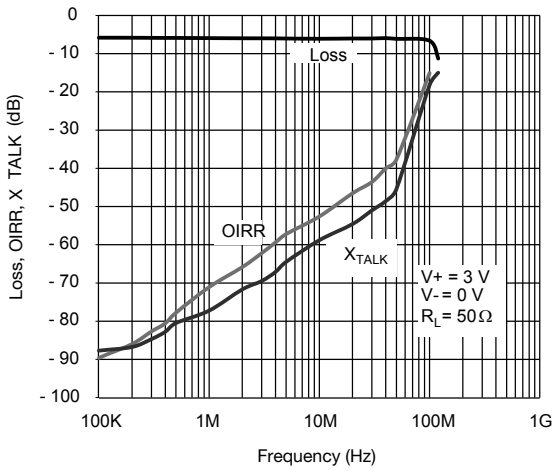
Leakage vs. Analog Voltage



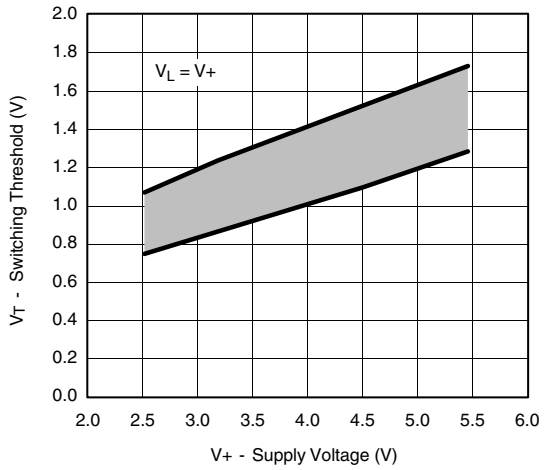
Switching Time vs. Temperature and Single Supply Voltage



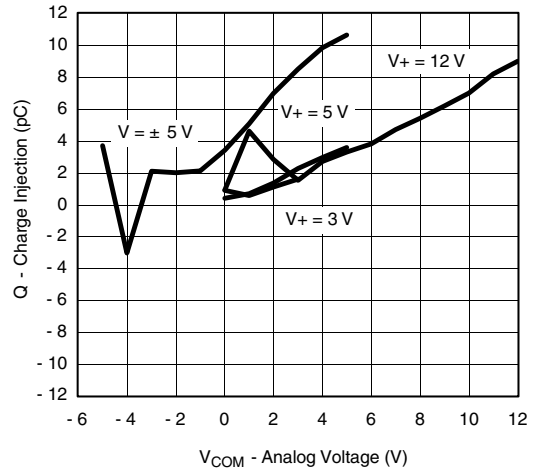
Switching Time vs. Temperature and Dual Supply Voltage



Insertion Loss, Off -Isolation Crosstalk vs. Frequency



Switching Threshold vs. Supply Voltage



Charge Injection vs. Analog Voltage)

SCHEMATIC DIAGRAM (Typical Channel)

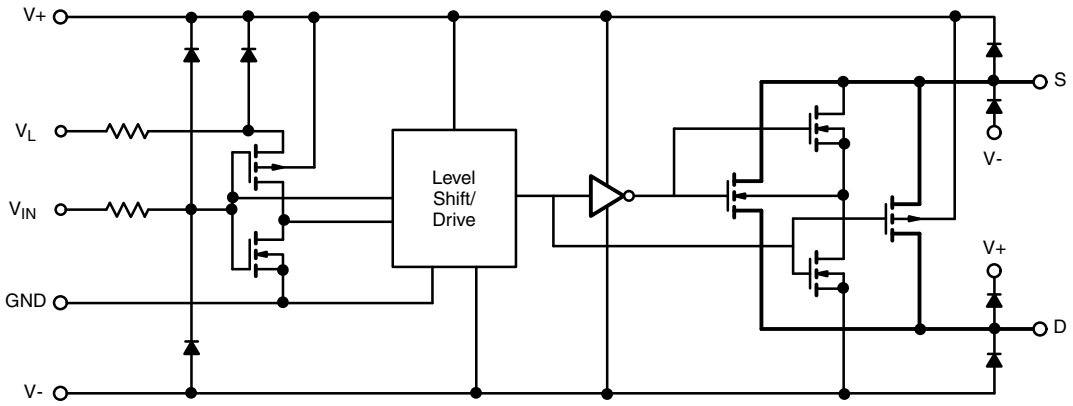
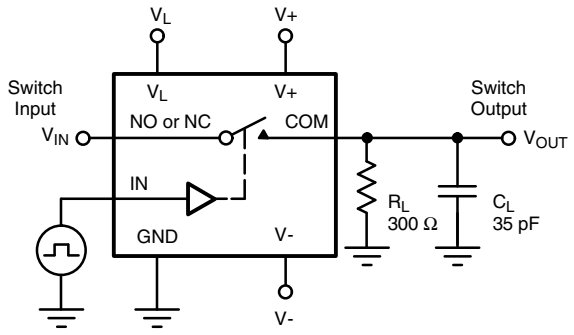


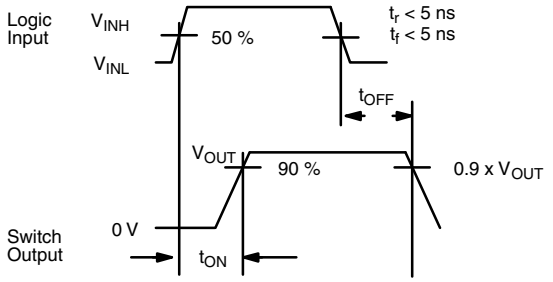
Figure 1.

TEST CIRCUITS



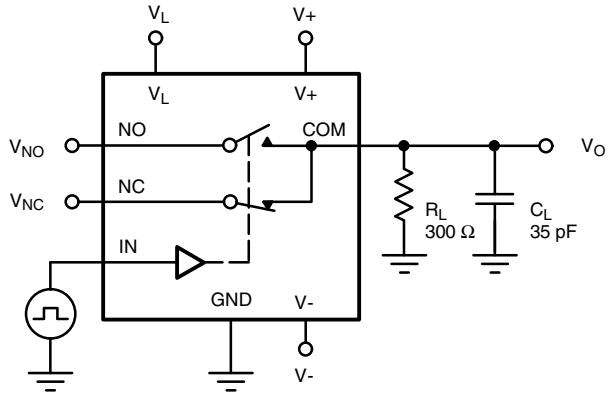
C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_{IN} \frac{R_L}{R_L + R_{ON}}$$



Note: Logic input waveform is inverted for switches that have the opposite logic sense control

Figure 2. Switching Time



C_L (includes fixture and stray capacitance)

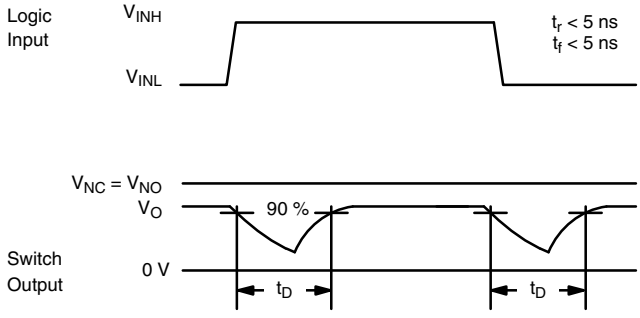


Figure 3. Break-Before-Make (DG419L)

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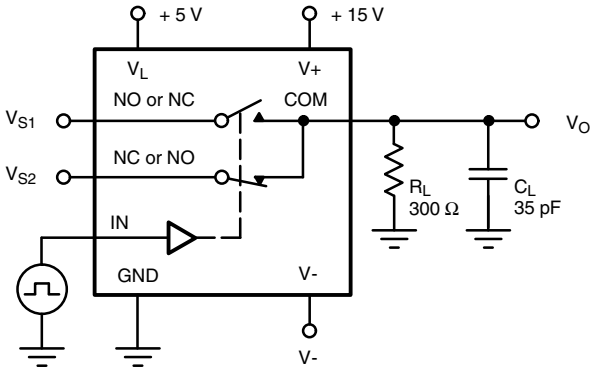
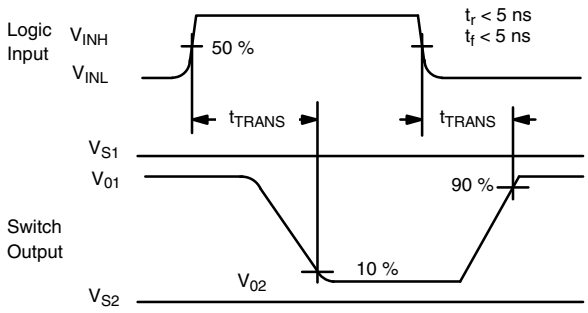
TEST CIRCUITS

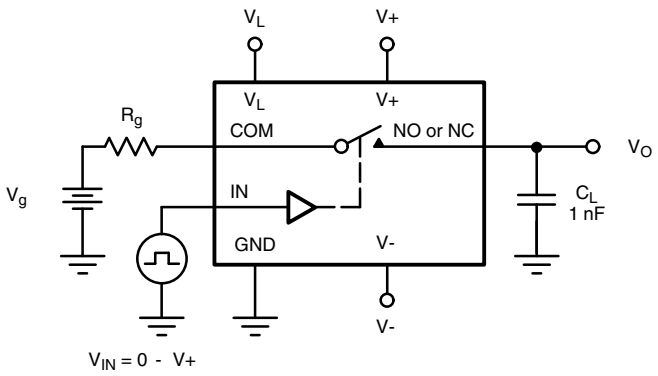


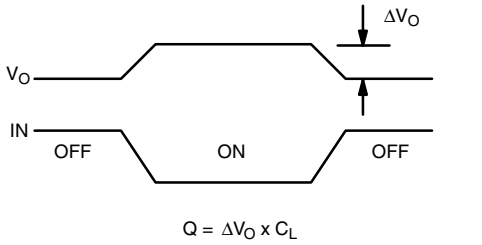


C_L (includes fixture and stray capacitance)

$$V_O = V_S \frac{R_L}{R_L + R_{ON}}$$

Figure 4. Transition Time (DG419L)

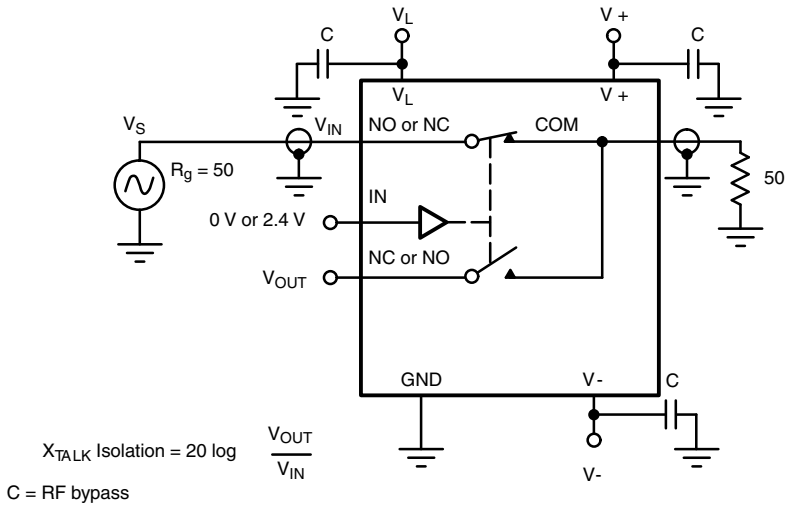




$Q = \Delta V_O \times C_L$

IN dependent on switch configuration Input polarity determined by sense of switch.

Figure 5. Charge Injection



X_{TALK} Isolation = 20 log $\frac{V_{OUT}}{V_{IN}}$

C = RF bypass

Figure 6. Crosstalk (DG419L)

TEST CIRCUITS

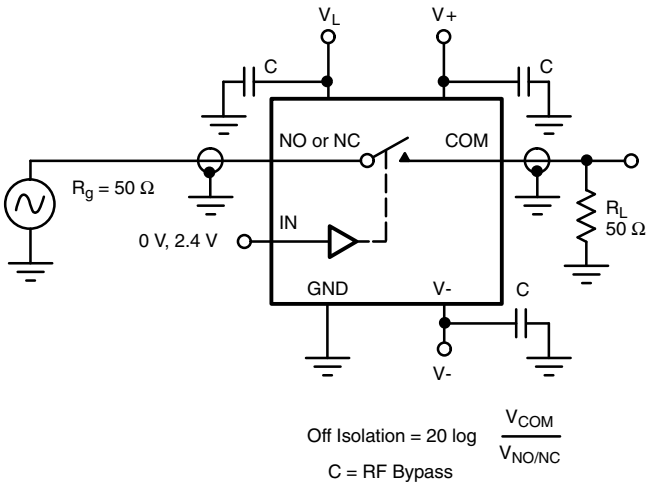


Figure 7. Off Isolation

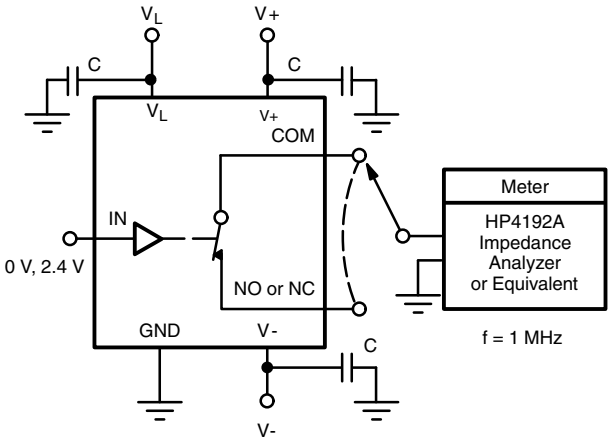
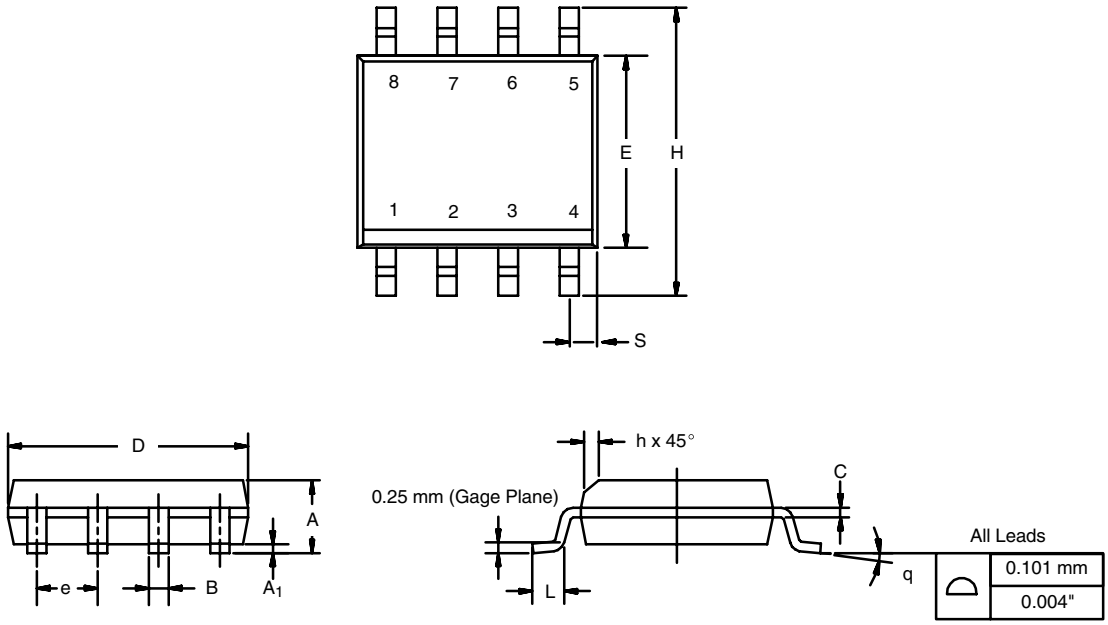


Figure 8. Source/Drain Capacitances

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71763.

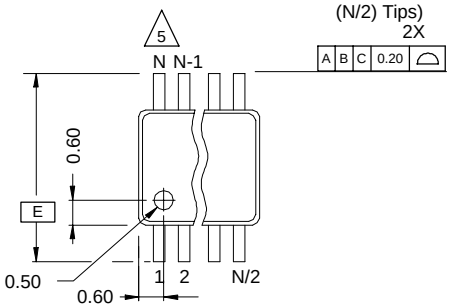
SOIC (NARROW): 8-LEAD
JEDEC Part Number: MS-012



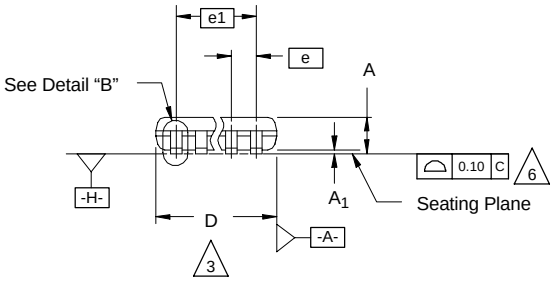
DIM	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A_1	0.10	0.20	0.004	0.008
B	0.35	0.51	0.014	0.020
C	0.19	0.25	0.0075	0.010
D	4.80	5.00	0.189	0.196
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.020
L	0.50	0.93	0.020	0.037
q	0°	8°	0°	8°
S	0.44	0.64	0.018	0.026
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498				

MSOP: 8-LEADS

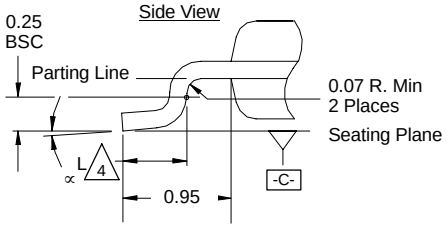
JEDEC Part Number: MO-187, (Variation AA and BA)



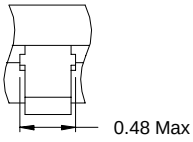
Top View



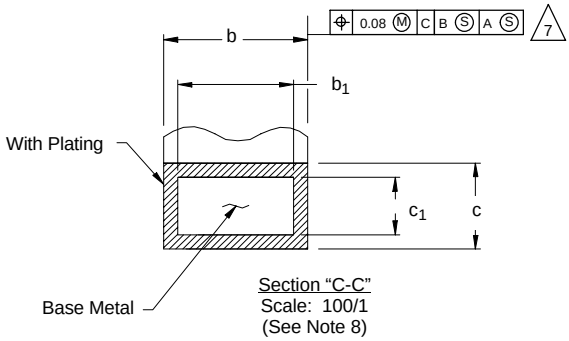
Side View



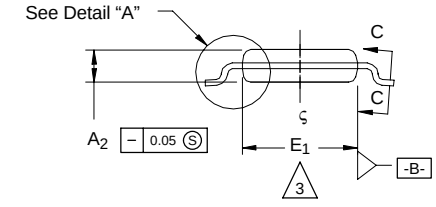
Detail "A"
(Scale: 30/1)



Detail "B"
(Scale: 30/1)
Dambar Protrusion



Section "C-C"
Scale: 100/1
(See Note 8)



End View

NOTES:

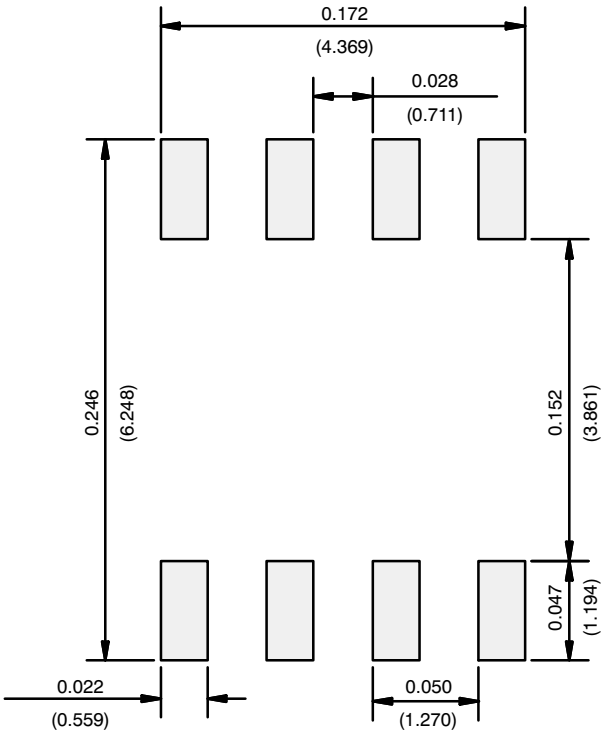
1. Die thickness allowable is 0.203 ± 0.0127.
2. Dimensioning and tolerances per ANSI.Y14.5M-1994.
3. Dimensions "D" and "E_1" do not include mold flash or protrusions, and are measured at Datum plane -H- , mold flash or protrusions shall not exceed 0.15 mm per side.
4. Dimension is the length of terminal for soldering to a substrate.
5. Terminal positions are shown for reference only.
6. Formed leads shall be planar with respect to one another within 0.10 mm at seating plane.
7. The lead width dimension does not include Dambar protrusion. Allowable Dambar protrusion shall be 0.08 mm total in excess of the lead width dimension at maximum material condition. Dambar cannot be located on the lower radius or the lead foot. Minimum space between protrusions and an adjacent lead to be 0.14 mm. See detail "B" and Section "C-C".
8. Section "C-C" to be determined at 0.10 mm to 0.25 mm from the lead tip.
9. Controlling dimension: millimeters.
10. This part is compliant with JEDEC registration MO-187, variation AA and BA.
11. Datums -A- and -B- to be determined Datum plane -H- .
12. Exposed pad area in bottom side is the same as teh leadframe pad size.

N = 8L

Dim	MILLIMETERS			Note
	Min	Nom	Max	
A	-	-	1.10	
A_1	0.05	0.10	0.15	
A_2	0.75	0.85	0.95	
b	0.25	-	0.38	8
b_1	0.25	0.30	0.33	8
c	0.13	-	0.23	
c_1	0.13	0.15	0.18	
D	3.00 BSC			3
E	4.90 BSC			
E_1	2.90	3.00	3.10	3
e	0.65 BSC			
e_1	1.95 BSC			
L	0.40	0.55	0.70	4
N	8			5
∝	0°	4°	6°	

ECN: T-02080—Rev. C, 15-Jul-02
DWG: 5867

RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads
Dimensions in Inches/(mm)

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